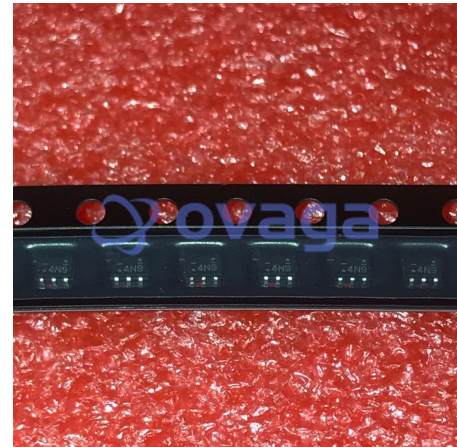


Trans MOSFET N-CH 20V 1.2A 6Pin SC-70 T/R

Manufacturers	<u>ON Semiconductor, LLC</u>
Package/Case	SC-70-6
Product Type	Transistors
RoHS	Green
Lifecycle	



Images are for reference only

Please submit RFQ for FDG1024NZ or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

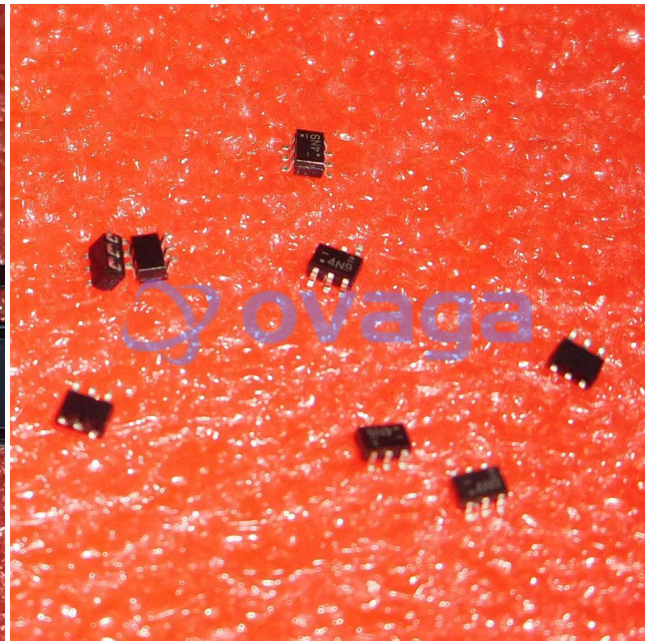
This dual N-Channel logic level enhancement mode field effect transistors are produced using a proprietary, high cell density, DMOS technology. This very high density process is especially tailored to minimize on-state resistance. This device has been designed especially for low voltage applications as a replacement for bipolar digital transistors and small signal MOSFETs. Since bias resistors are not required, this dual digital FET can replace several different digital transistors, with different bias resistor values.

Features

Very low level gate drive requirements allowing operation in 1.5 V circuits ($V_{GS(th)} < 1 V$)

Application

ONSEMI

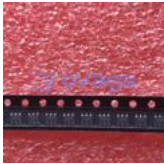


Related Products



[FDC645N](#)

ON Semiconductor, LLC
SSOT-6



[FDC6305N](#)

ON Semiconductor, LLC
SSOT-6



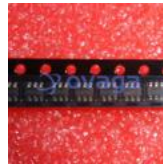
[FDD8647L](#)

ON Semiconductor, LLC
TO-252-3



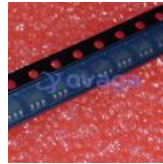
[FDD5N50NZTM](#)

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[FDC637BNZ](#)

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